

# Device Modeling Report

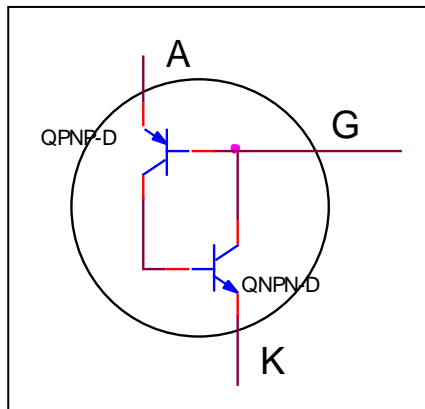
COMPONENTS: Programmable Unijunction Transistor  
PART NUMBER: TN41A  
MANUFACTURER: TOSHIBA



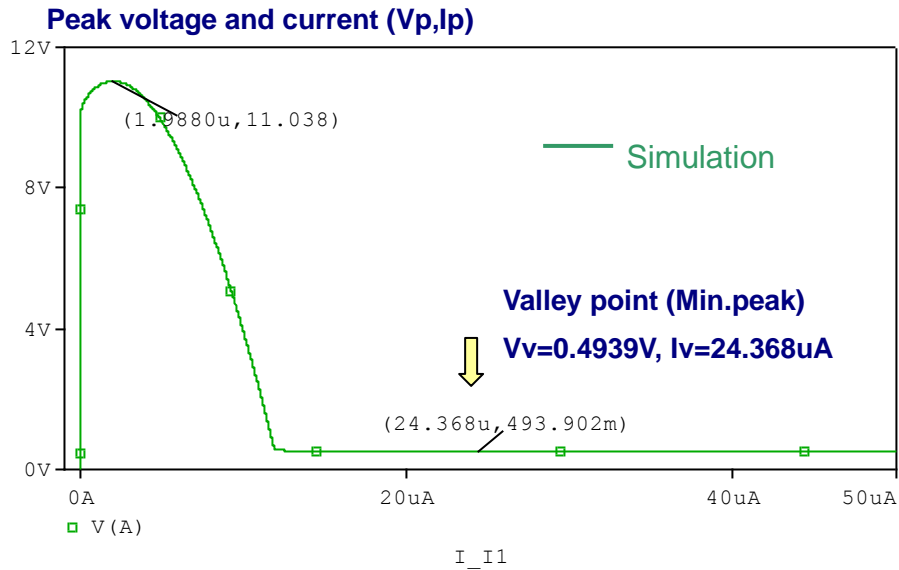
**Bee Technologies Inc.**

| Pspice model parameter | Model description                               |
|------------------------|---|
| IS                     | Saturation Current                              |
| ISE                    | Non-ideal Base-Emitter Diode Saturation Current |
| RC                     | Series Collector Resistance                     |
| TR                     | Reverse transit time                            |
| TF                     | Forward Transit Time                            |

### Equivalent circuit



## Peak Voltage (Vp) and Peak Current (Ip) Characteristics

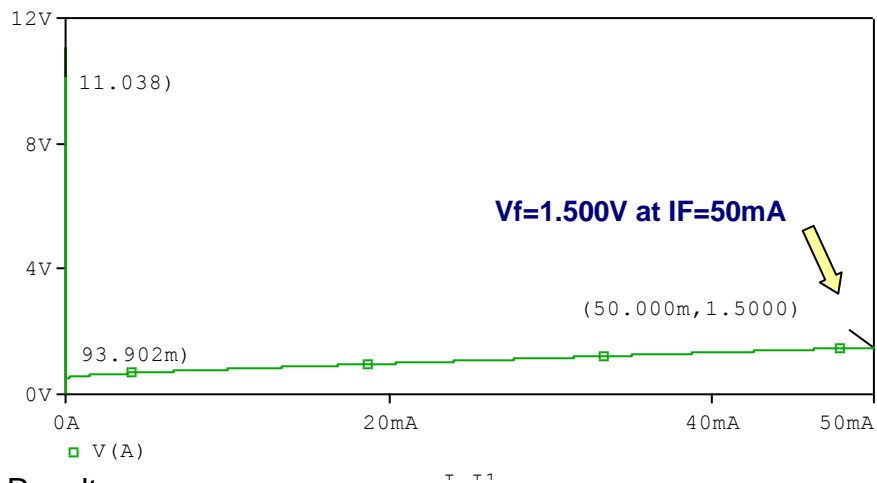


Simulation Result

$V_p=11.038(V)$  at  $I_p=2u(A)$

SPEC:  $V_p=10.2(V)$  to  $11.6(V)$  at  $I_p(max.)=2u(A)$

## Forward Voltage Characteristics



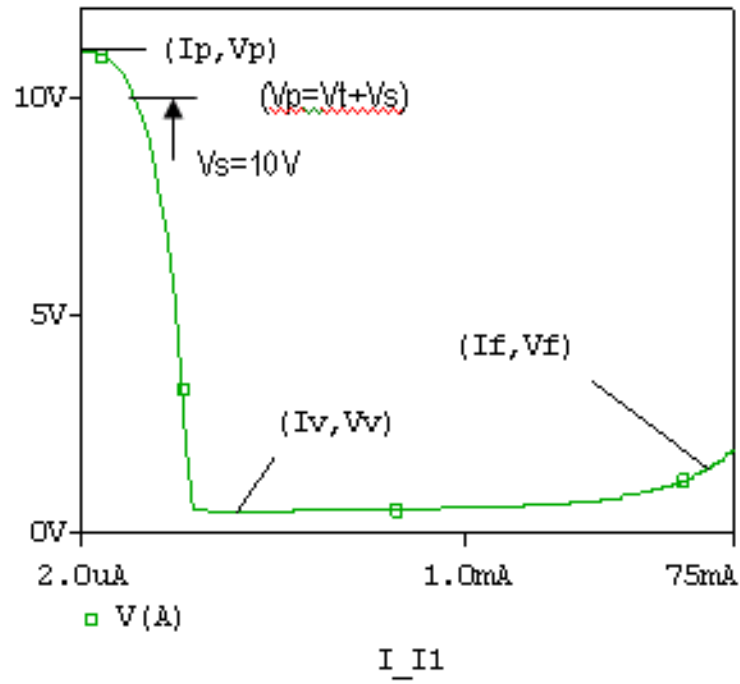
Simulation Result

$V_f=1.5(V)$  at  $I_f=50m(A)$

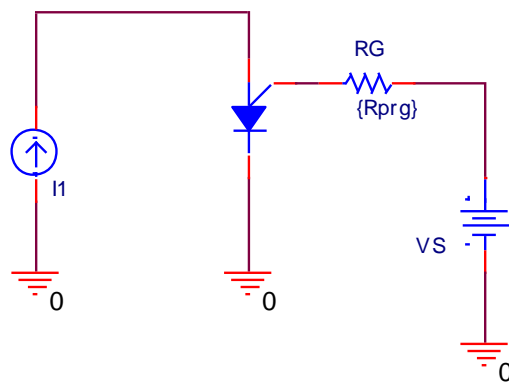
SPEC:  $V_f=1.5(V)MAX.$  at  $I_f=50m(A)$

# Voltage and Current Characteristics

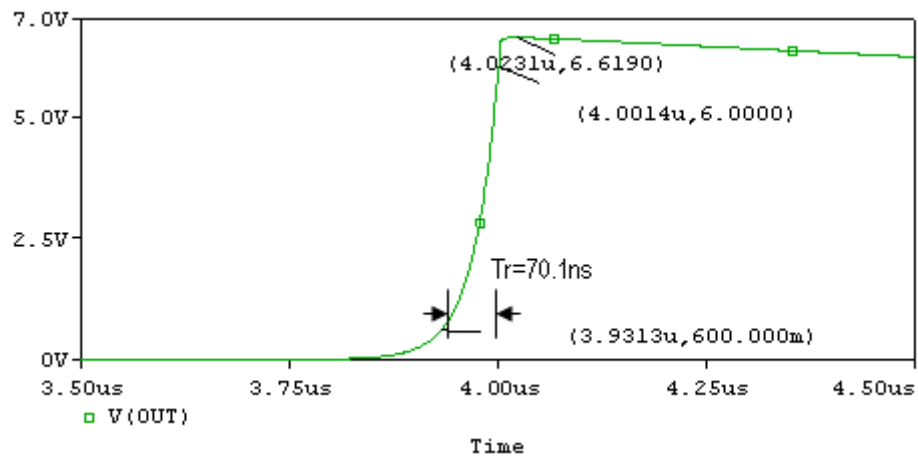
# Reference



## Evaluation Circuit



## Pulse Output Voltage and Pulse Output Rise Time



$V_o=6.619(V)$  at  $V_i=20(V)$ ,  $C_t=0.2u(F)$

SPEC:  $V_o=6(V)$  to  $10(V)$  at  $V_i=20(V)$ ,  $C_t=0.2u(F)$

$t_r=70.1(ns)$  at  $V_i=20(V)$ ,  $C_t=0.2u(F)$

SPEC:  $t_r=70(ns)$  to  $80(ns)$  at  $V_i=20(V)$ ,  $C_t=0.2u(F)$

### Evaluation circuit

